NSN 5961-01-324-1159

81349-mil-prf-19500/472 government specification

Shelf Life:

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Inclosure Material:

Overall Length:

Metal



View Online at https://aerobasegroup.com/nsn/5961-01-324-1159

0.260 inches
Terminal Length:
1.750 inches
Overall Diameter:
0.370 inches
End Application:
Aircraft, b-2 bomber (atb)
Internal Configuration:
Junction contact-darlington connected
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-33
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case and quality assurance level txv
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter reverse voltage and 12.0 emitter to base voltage, static,
collector open
Current Rating Per Characteristic:
10.00 amperes source cutoff current and 0.50 amperes source cutoff current
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
4 uninsulated wire lead
Specification Data:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.